

Title (en)

SINGLE CRYSTAL WELDING OF DIRECTIONALLY SOLIDIFIED MATERIALS

Title (de)

EINKRISTALLINES SCHWEISSEN VON DIREKTIONAL VERFESTIGTEN WERKSTOFFEN

Title (fr)

SOUDE MONOCRISTALLIN DE MATERIAUX A SOLIDIFICATION DIRECTIONNELLE

Publication

**EP 2496380 A1 20120912 (DE)**

Application

**EP 10776651 A 20101103**

Priority

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- EP 2010066733 W 20101103

Abstract (en)

[origin: WO2011054864A1] The invention relates to the targeted selection of process parameters for laser welding, feeding, laser power beam diameter, and powder mass flow, wherein the temperature gradient substantially decisive for single crystal growth during laser application welding can be set deliberately.

IPC 8 full level

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Citation (search report)

See references of WO 2011054864A1

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